

**Keldysh Institute of Applied Mathematics  
Russian Academy of Sciences**



# **Computer Simulation of the Interaction of Metal Nanoparticles with a Substrate**

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Technologies in Science and Education"  
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# Goals and tasks

**Main goal** is a development of supercomputer technology for simulation of complex processes in technical micro- and nanosystems

**The technology includes the following components:**

- multi-scale mathematical models set;
- parallel numerical algorithms base;
- parallel software tools;
- applications in nanotechnologies.

**Achieved results:**

A multi-level multi-scale approach to the calculations of actual problems of gas and plasma dynamics has been developed and tested.

2. Numerical methods for solving both independent and related problems that determine the behavior of the system at various scale levels.

3. Parallel algorithms and software packages for simulation of multi-scale problems.

4. A database on the properties of substances that includes: parameters of the gas medium, kinetic parameters of gases and metals, parameters for determining of boundary conditions.

5. Model calculations for some actual nanotechnology problems.

# Metallic Nanoparticles Spraying

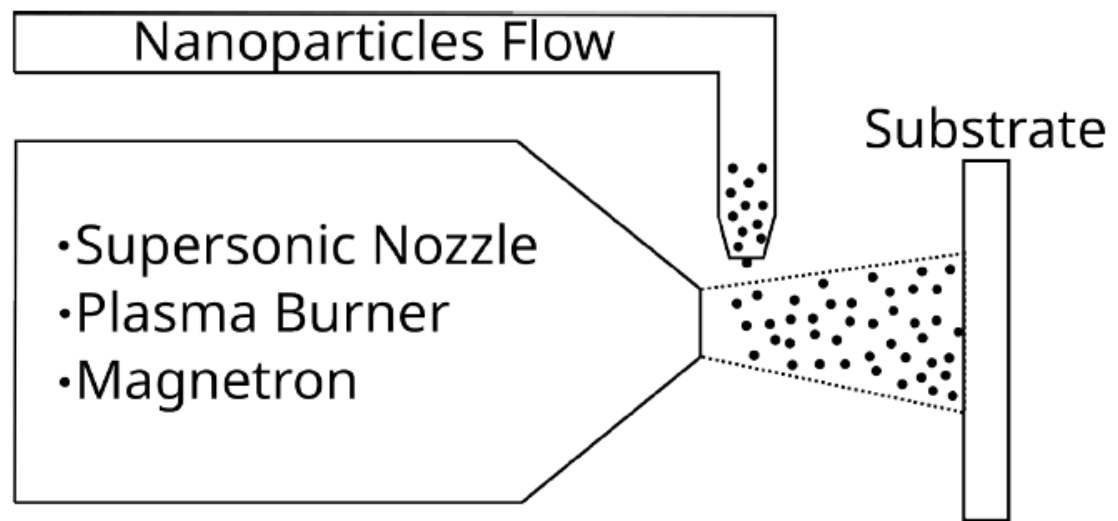
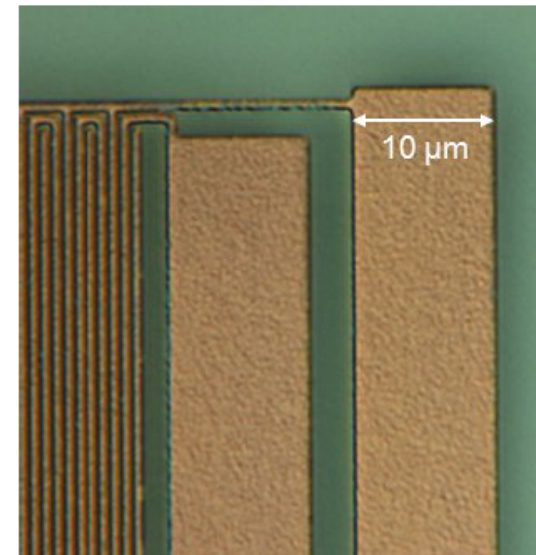
## **Application:**

- **protective coatings**
- **microelectronics**
- **medical equipment**
- **bio-sensors**
- etc.**

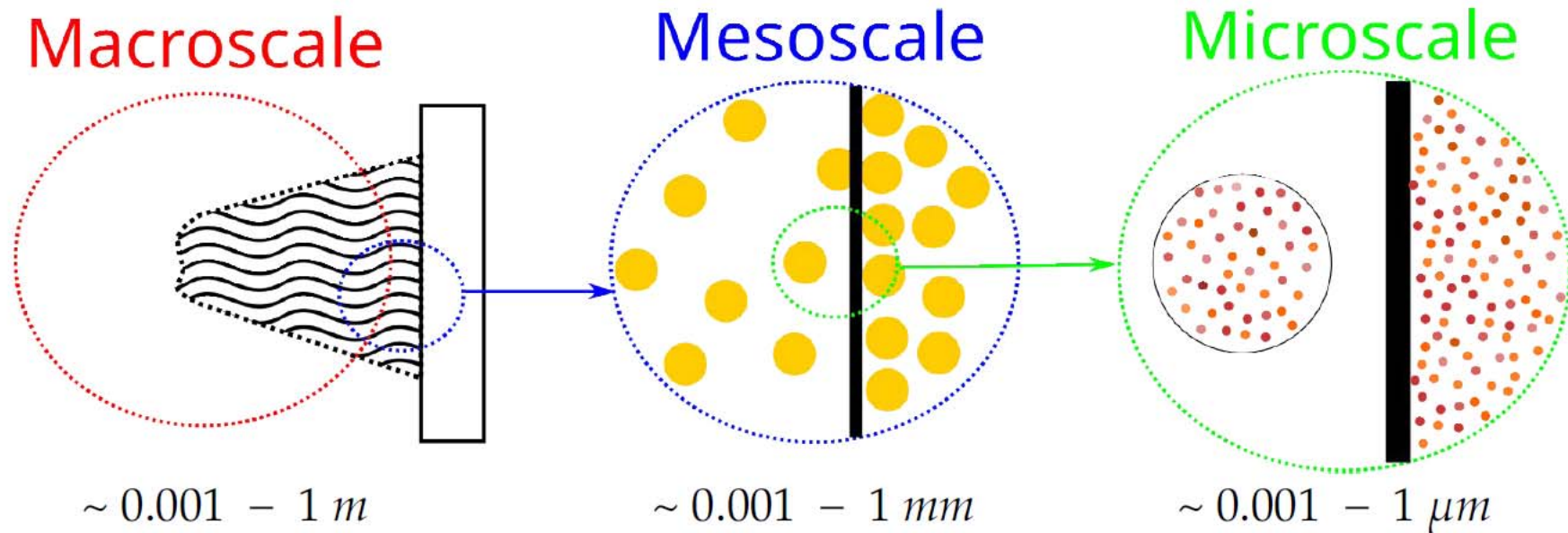
## **Technological methods:**

- **supersonic cold gasdynamics spraying**
- **plasma spraying**
- **magnetron spraying**
- etc.**

Birkholz, M.; Ehwald, K.-E.; Wolansky, D.; Costina, I.; Baristiran-Kaynak, C.; Fröhlich, M.; Beyer, H.; Kapp, A.; Lisdat, F. (15 March 2010). "Corrosion-resistant metal layers from a CMOS process for bioelectronic applications". *Surface and Coatings Technology*. **204** (12–13): 2055–2059.



# Multiscale Analysis



## Modeling approaches:

**Macroscopic: Continuum Mechanics Models**

**Mesoscopic: Particle Methods**

**Microscopic: Molecular Dynamics**

**Macroscopic and Microscopic: CMM + MD**

**Macro-, Meso- and Microscopic: CMM + PM + MD**

# Mathematical Models and Numerical Methods

## Mathematical models:

### Macroscopic:

- Navier-Stokes equations
- Quasi Gas Dynamics equations
- Maxwell's electrodynamics

### Mesoscopic:

- Large particles
- Smoothed particles
- Particle in cells
- Particle clouds

### Microscopic:

- Classic Molecular Dynamics
- Quantum Molecular Dynamics
- Hartree-Fock approach
- Variational models

## Numerical approaches:

- Splitting on physical processes
- Transitions between scales

### Macroscopic:

- Cartesian grids
- Unstructured grids
- Hybrid block grids
- Finite Volume Method
- Explicit or Implicit Time schemes
- Spatial and Nonlinearity Iterations

### Mesoscopic:

- Newton dynamics

### Microscopic:

- Molecular dynamics equations
- Interaction potentials
- Spectral methods
- Grid methods
- Density functional method
- Method of atomic orbitals

# Parallel technologies and Software tools

## Parallel technologies:

- Domain decomposition
- Load balancing
- Hybrid computations

## Parallel environments:

- MPI
- OpenMP
- CUDA
- Hybrids

## Programming languages:

- C/C++
- Fortran

## Supercomputers:

- K100
- K10
- K60CPU
- K60GPU

## Self-maid software:

### GIMM\_NANO tools:

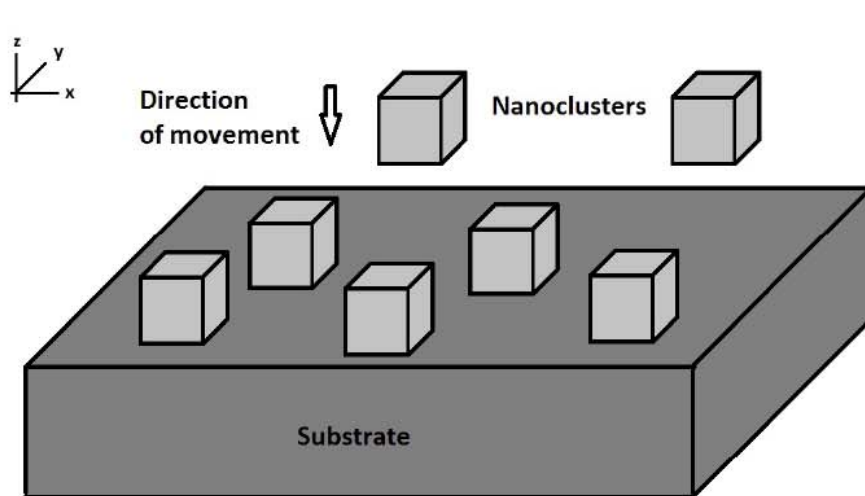
- GIMM\_Main\_GUI
- GIMM\_Mesh\_Gen\_Tool
- GIMM\_Visualizer
- GIMM\_Jobs\_Management
- GIMM\_IO\_Lib
- GIMM\_APP\_MD\_CPU\_Gas\_Metal
- GIMM\_APP\_QGD\_CPU
- GIMM\_APP\_QGD\_MD\_CPU
- GIMM\_APP\_QGD\_MD\_CPU

### Web-solutions:

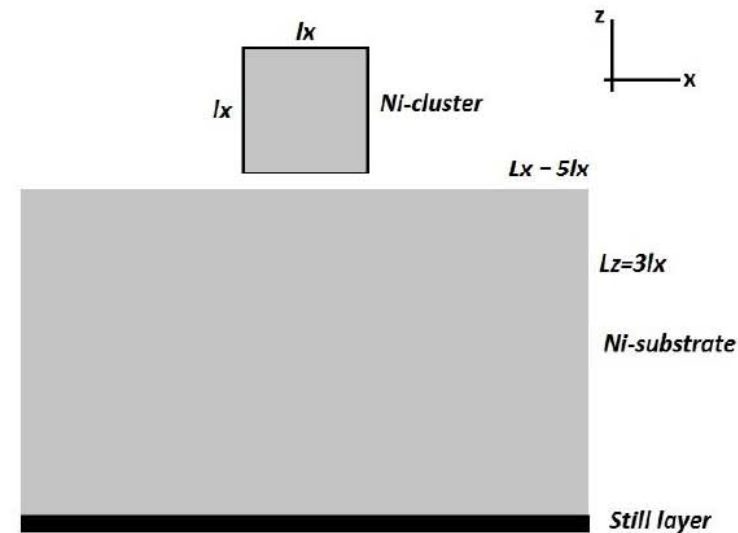
- KIAM\_WMCS
- KIAM\_MDVIS
- KIAM\_MoISDAG\_CPU
- KIAM\_MMD\_WUI
- KIAM\_DIGITAL\_TOOL\_SERVER
- KIAM\_DIGITAL\_TOOL\_CLIENT

# Mesososcopic solution

## Problem formulation



Model geometry of the problem

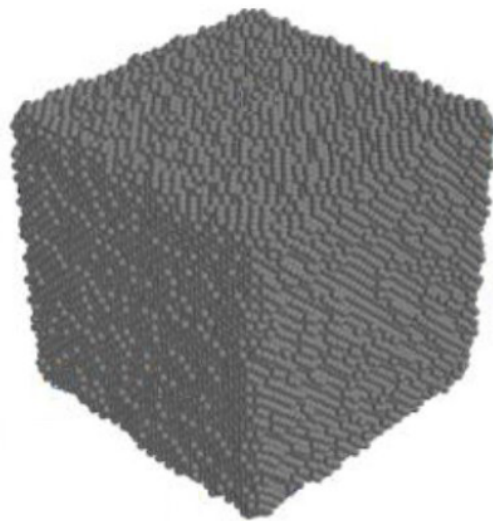


Computational Domain  
of preliminary  
numerical experiments

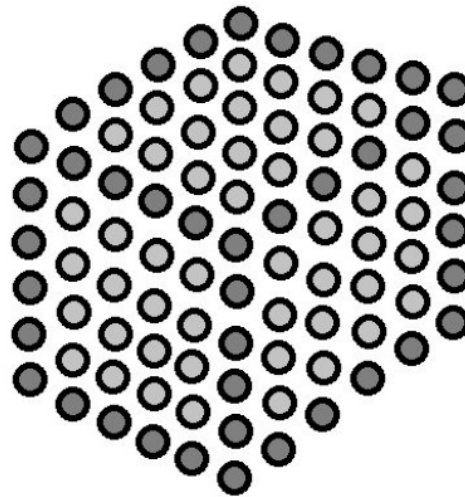
Nickel elementary  
cell on normal  
conditions:  
 $a = 0.35314 \text{ nm}$   
 $lx = 24 \cdot a = 8.475 \text{ nm}$



# Mesososcopic Approach



Real nanocluster



Nanospheroid model

Nanospheroid model (form-function):

$$\delta(\mathbf{r} - \mathbf{r}_{\alpha,k}) \approx C_k(t) \cdot \exp \left[ - \left| \mathbf{r} - \mathbf{r}_{\alpha,k} \right|^2 / R_{\alpha,k}^2 \right]$$

Neutral case (in electron units of mass and charge):

$$q_+ = + \left( \sqrt[3]{3N_a Z_a} \right)^2 \quad q_- = - \left( \sqrt[3]{3N_a Z_a} \right)^2$$

$$m_+ = N_a m_a / m_e \quad m_- = - \left( \sqrt[3]{3N_a Z_a} \right)^2$$

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$\mathbf{r}_{\alpha,k}$	– radius vector of k-spheroid of $\alpha$ sort
$\alpha = -, +$	– nanospheroid sort
$C_k(t)$	– normalization parameter
$R_{\alpha,k}$	– effective radius
$q_{\alpha,k} \equiv q_\alpha$	– charge of particle of $\alpha$ sort
$m_{\alpha,k} \equiv m_\alpha$	– mass of particle of $\alpha$ sort
$N_a, m_a, m_e$	– number and mass of ions, mass of electrons

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# Electromagnetics Field Equations

Maxwell equations:

$$\operatorname{div} \mathbf{B} = 0$$

$$\operatorname{div} (\varepsilon_a \mathbf{E}) = \rho$$

$$\frac{\partial \mathbf{B}}{\partial t} = - \operatorname{rot} \mathbf{E}$$

$$\frac{\partial}{\partial t} (\varepsilon_a \mathbf{E}) = \operatorname{rot} \left( \frac{1}{\mu_a} \mathbf{B} \right) - \mathbf{j}$$

Electric field as sum of wave processes and particles evolution:

$$\mathbf{E} = \mathbf{E}^{(w)} + \mathbf{E}^{(p)}$$

$$\mathbf{E}^{(p)} = - \nabla \varphi$$

$$\operatorname{div} (\varepsilon_a \mathbf{E}^{(w)}) = 0$$

$$\operatorname{div} (\varepsilon_a \nabla \varphi) = - \rho$$

$$\frac{\partial}{\partial t} (\varepsilon_a \mathbf{E}^{(w)}) = \operatorname{rot} \left( \frac{1}{\mu_a} \mathbf{B} \right) - \mathbf{j} - \frac{\partial}{\partial t} (\varepsilon_a \mathbf{E}^{(p)})$$

---

$\operatorname{div}, \operatorname{rot}$	– divergence and rotor
$\mathbf{B}$	– magnetic induction vector
$\varepsilon_a$	– absolute dielectric permeability of the medium
$\mathbf{E}$	– electric field strength vector
$\rho = \rho_e + \rho_i$	– volume charge density divided into positive and negative comp.
$\mu_a$	– absolute magnetic permeability of the medium
$\mathbf{j}$	– current density vector (generated by particles)
$\mathbf{E}^{(w)}$	– wave processes part of electric field strength
$\mathbf{E}^{(p)}$	– particles evolution part of field strength
$\varphi$	– quasi-static potential of electromagnetic field

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# Nanocluster Evolution Equations

Newton dynamic with the Lorentz force:

$$\frac{d\mathbf{r}_{\alpha,k}}{dt} = \mathbf{v}_{\alpha,k} \quad \frac{d\mathbf{p}_{\alpha,k}}{dt} = q_{\alpha,k} (\mathbf{E} + [\mathbf{v}_{\alpha,k} \times \mathbf{B}])$$

$$\mathbf{p}_{\alpha,k} = m_{\alpha,k} \mathbf{v}_{\alpha,k}$$

$$\rho_{\alpha} = \sum_{k=1}^{N_{\alpha}} q_{\alpha,k} \delta(\mathbf{r} - \mathbf{r}_{\alpha,k})$$

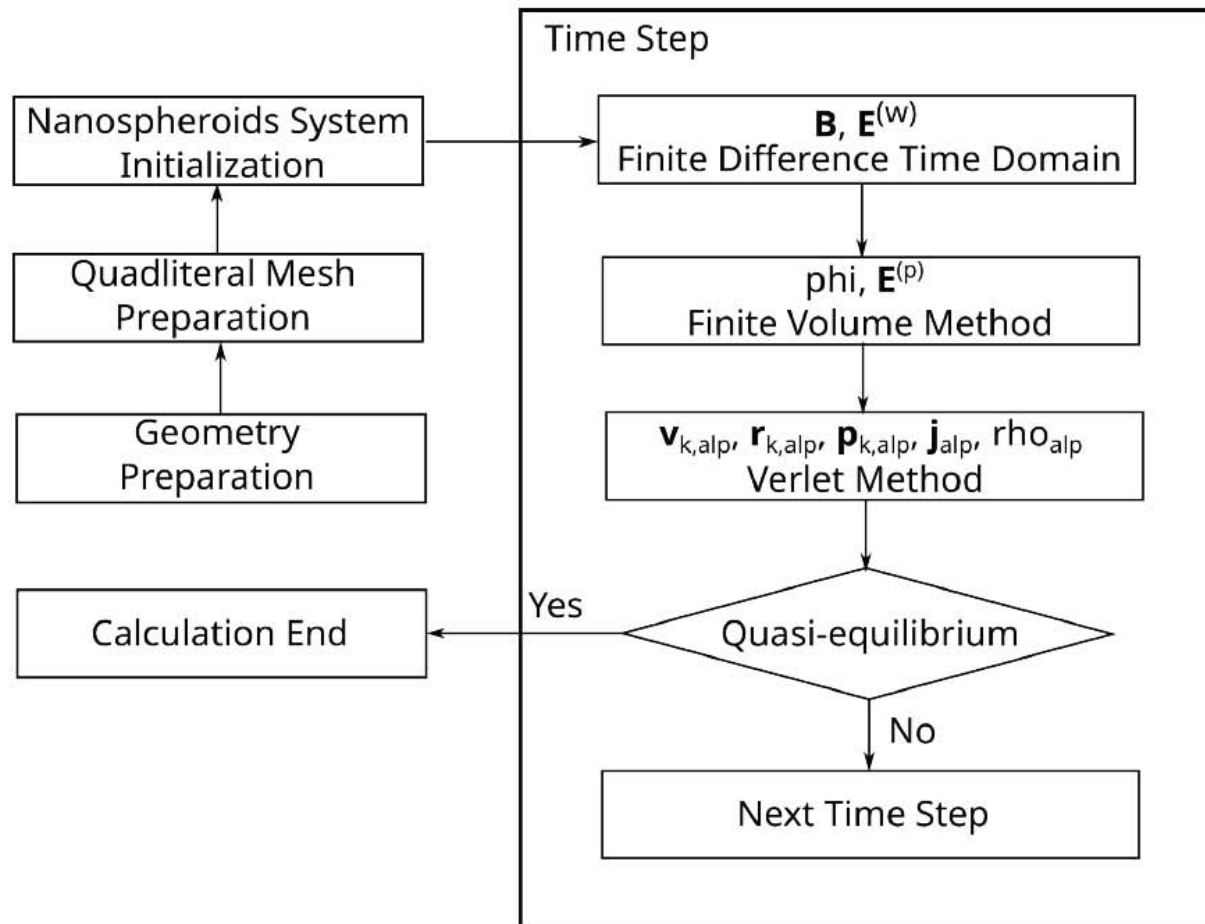
$$\mathbf{j}_{\alpha} = \sum_{k=1}^{N_{\alpha}} q_{\alpha,k} \delta(\mathbf{r} - \mathbf{r}_{\alpha,k}) \mathbf{v}_{\alpha,k}$$

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$\mathbf{r}_{\alpha,k}$	– radius vector of k-spheroid of $\alpha$ sort
$t$	– time
$\mathbf{v}_{\alpha,k}$	– velocity vector of k-spheroid of $\alpha$ sort
$\mathbf{p}_{\alpha,k}$	– momentum vector of k-spheroid of $\alpha$ sort
$\alpha = -, +$	– nanospheroid sort
$k = 1, \dots, N_{\alpha}$	– index of nanospheroid of $\alpha$ sort
$m_{\alpha,k} = m_{\alpha}$	– mass of nanospheroid of $\alpha$ sort
$q_{\alpha,k} = q_{\alpha}$	– charge of nanospheroid of $\alpha$ sort
$N_{\alpha}$	– number of nanospheroids of $\alpha$ sort

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# Numerical Algorithm



boundary conditions

$\mathbf{E}$ ,  $\mathbf{B}$  - inlet TE-wave, absorbing  
 $\mathbf{r}_{\alpha,k}$ ,  $\mathbf{v}_{\alpha,k}$  - free-out,  
 adhesion or absorption

Initial Conditions

$$\mathbf{E}^{(w)} = 0$$

$$\mathbf{B} = 0$$

$$\mathbf{E}^{(p)} = \mathbf{E}_0(x,y,z)$$

$$\mathbf{r}_{\alpha,k} = \mathbf{r}_{0,\alpha,k}$$

$$\mathbf{v}_{\alpha,k} = \mathbf{v}_{Maxwell,\alpha,k}$$

# Numerical methods and parallel solution

1. Unstructured grids
2. Finite Difference Time Difference scheme for Maxwell equations
3. Domain decomposition for cluster nodes
4. Sub-domain decomposition for CPU threads

## Domain decomposition

The Peano's curves technique (MPI-processes)

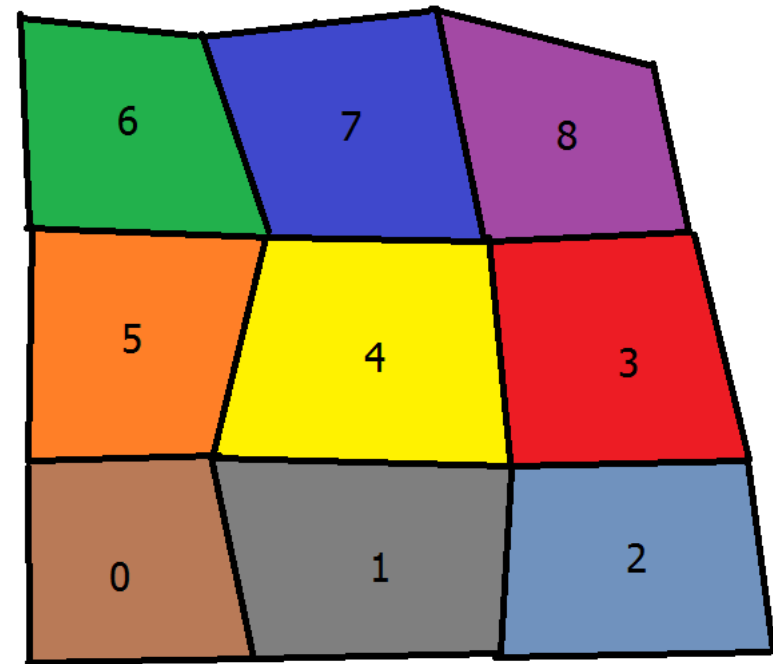
$$p = p_1 p_2 p_3$$

$$\frac{p_1}{p_2} \approx \frac{N_1}{N_2} \quad \frac{p_1}{p_3} \approx \frac{N_1}{N_3} \quad \frac{p_2}{p_3} \approx \frac{N_2}{N_3}$$

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$p$	– total number of threads
$p_1, p_2, p_3$	– threads per direction (x,y,z)
$N_1, N_2, N_3$	– number of mesh elements per direction (x,y,z)

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# Parallel realization for particles

1. Conservative Adams Scheme for Newton's equations
2. Domain decomposition for cluster nodes
3. Local load-balancing algorithm into each cluster node
4. Global load-balancing algorithm between cluster nodes

Load balancing algorithm:

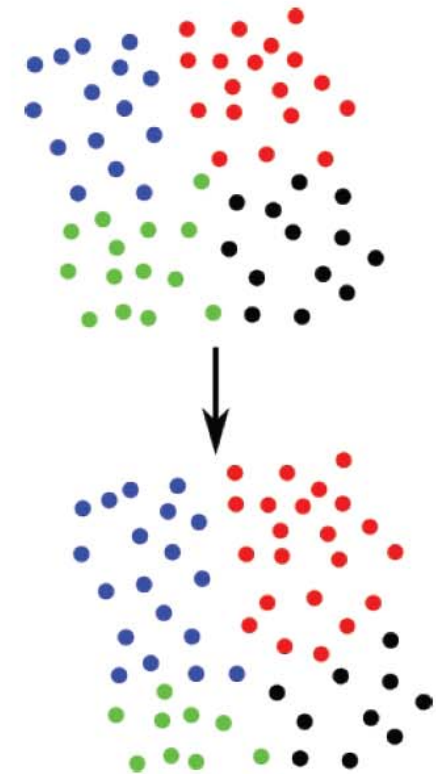
- 1) Initial uniform splitting and calculation by  $p$ -threads
- 2) Determining the time  $t_k$  ( $k = 0, \dots, p-1$ ) of  $k$ -thread computing
- 3) Calculation of the average execution time and relative times dispersion:

$$t_s = \frac{1}{p} \sum_{k=0}^{p-1} t_k, \quad \sigma = \max_k |(t_k - t_s)/t_s| \cdot 100\%$$

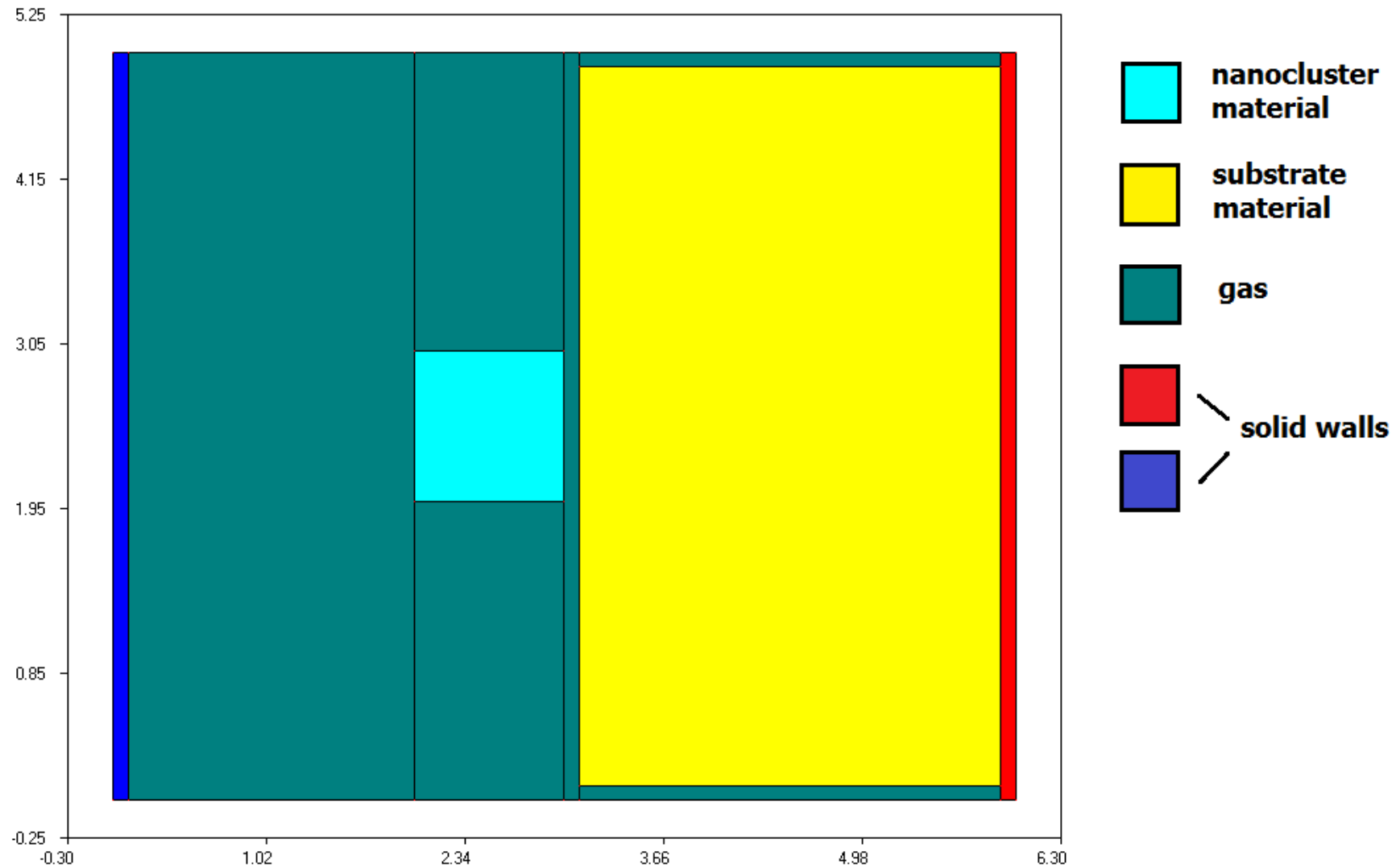
- 4) If  $\sigma > 5\%$  redistribution of nanospheroids by threads:

$$N_k = N_k + \gamma N \cdot \frac{q_k}{Q}, \quad q_k = \frac{N_k}{t_k}, \quad k = 0, \dots, p-2$$

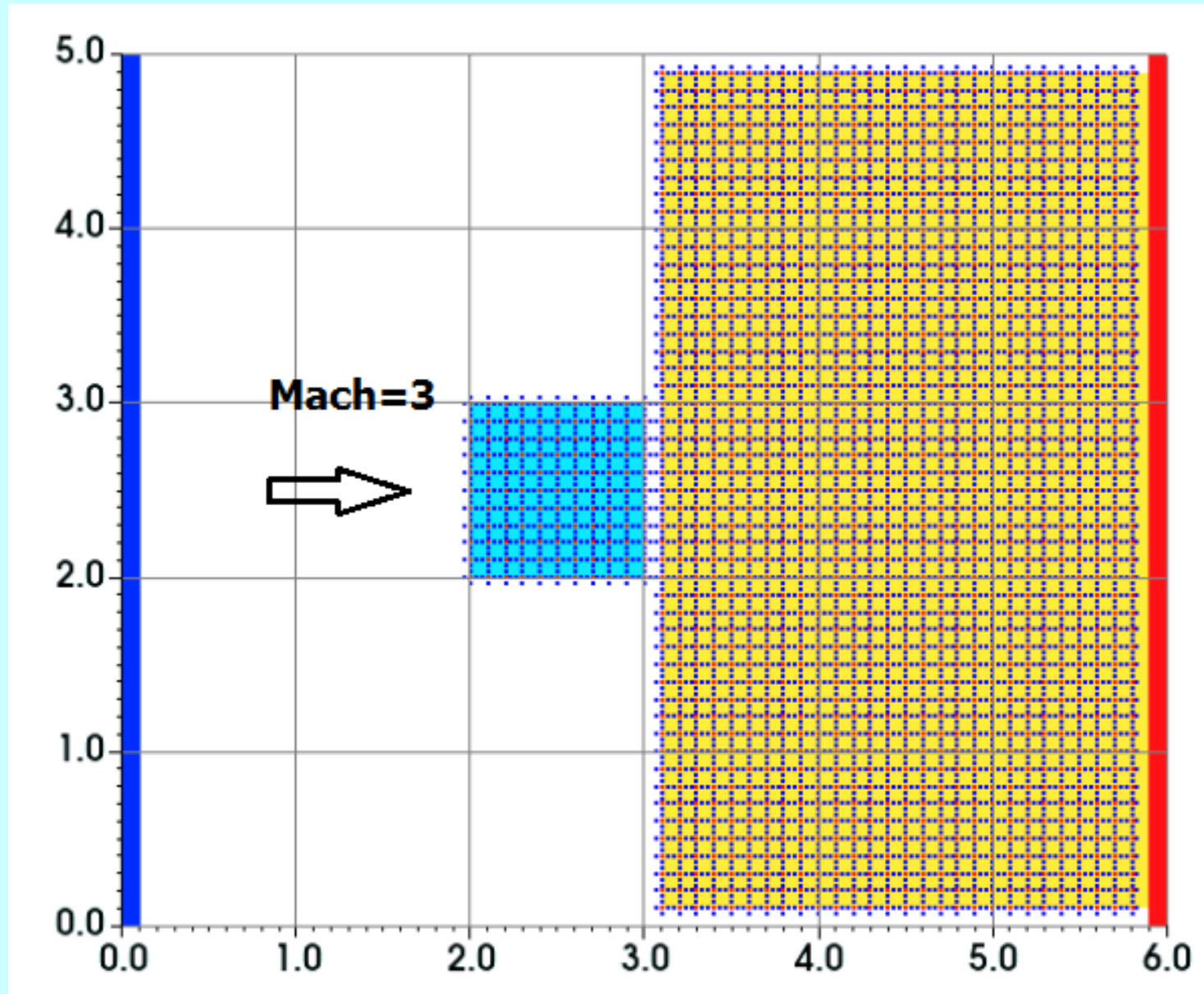
$$N_{p-1} = N - \sum_{k=0}^{p-2} N_k, \quad N = N_+ + N_-, \quad Q = \sum_{k=0}^{p-2} q_k, \quad \gamma \sim 0.05$$



# Interaction of the nanocluster with the substrate

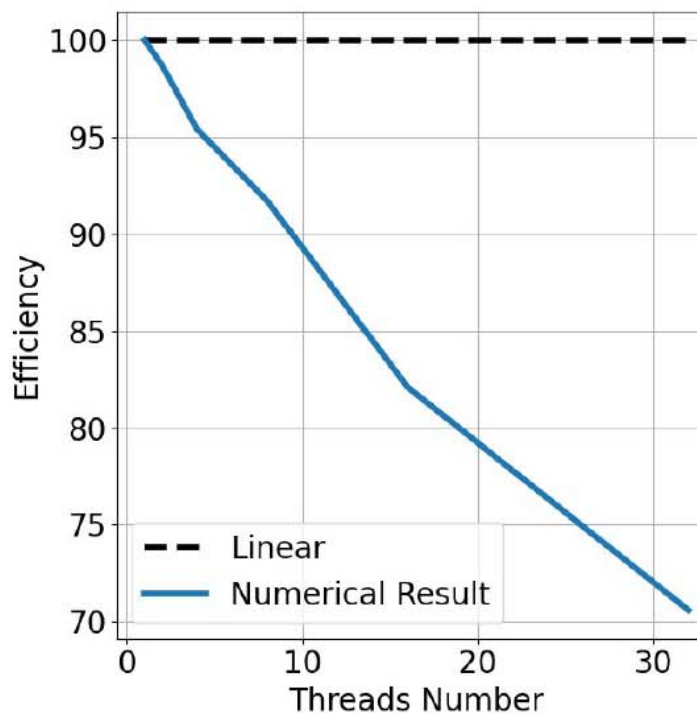
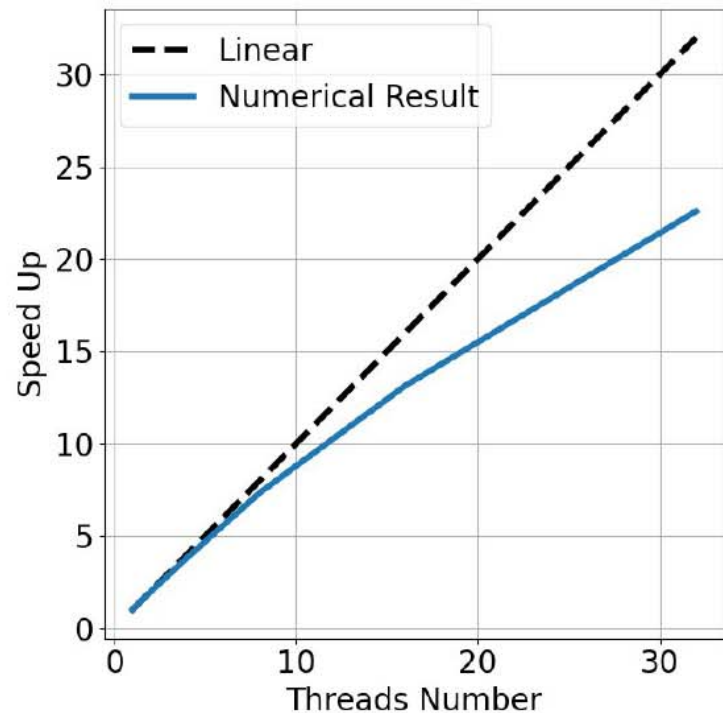


# Initial particles distribution





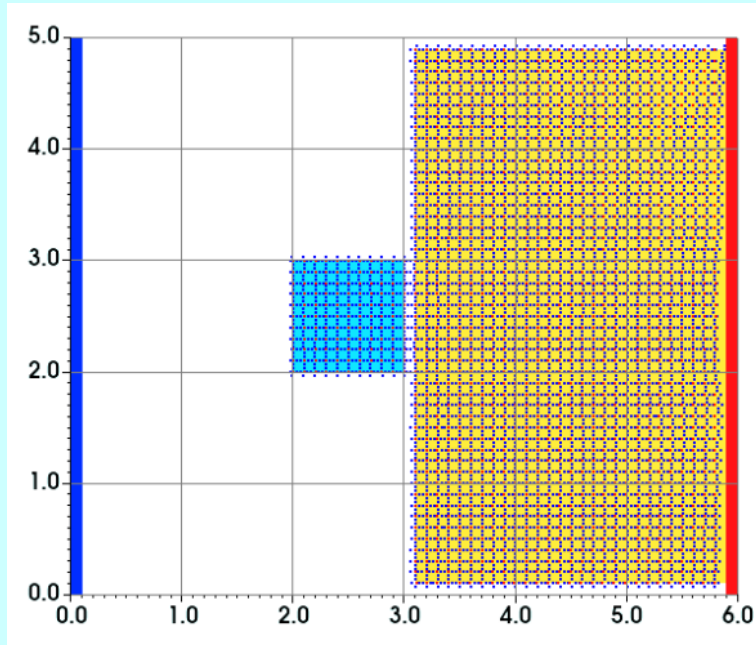
# Speed UP and Efficiency for one cluster node



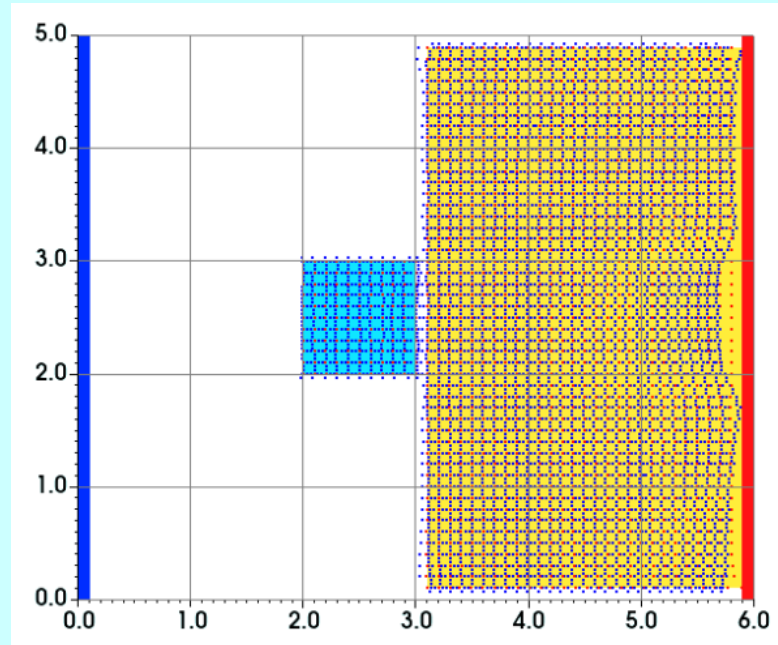
Node of K60 GPU:  
2 x Intel Xeon Gold 6142  
v4, 16 threads  
Task: quasi-equilibrium  
(20000 time steps) of  
25386 nanospheroids

# Simulation results

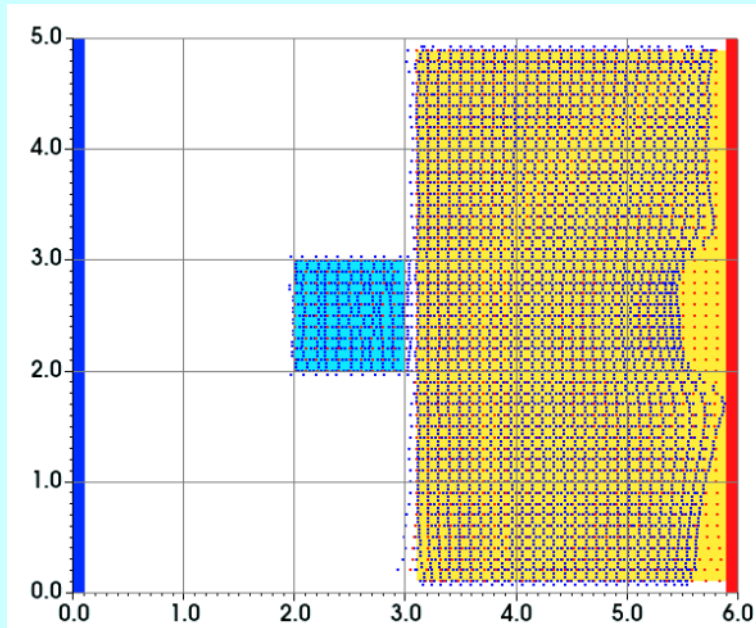
1 ns



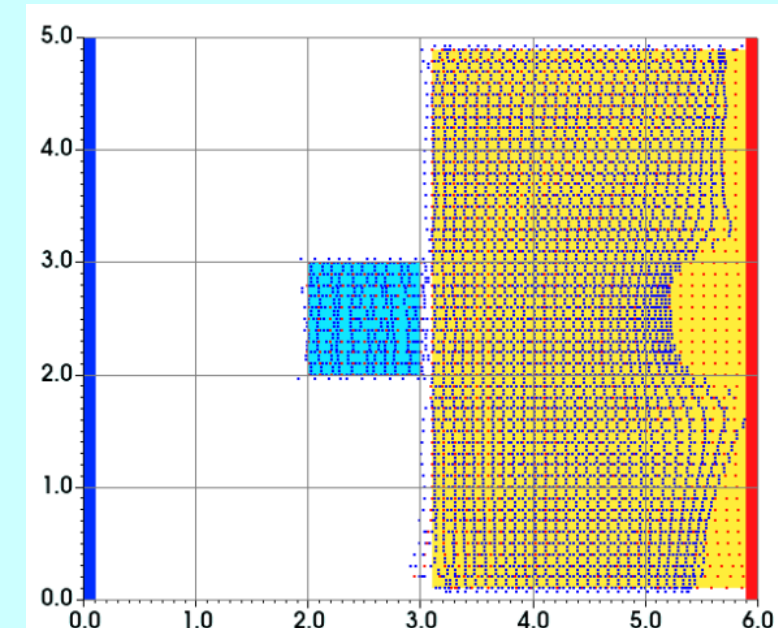
2 ns



3 ns



4 ns



# Conclusion

- The complex technology of supercomputer modeling of problems of deposition of metal nanoparticles on substrates is presented.
- A mesoscopic approach to solving spraying problems is considered.
- A sputtering model combining macroscopic and microscopic levels based on Maxwell's equations and equations of particle dynamics is proposed.
- Numerical methods have been developed that combine the grid method FDTD and particle methods PIC and SPE.
- Parallel algorithms for implementing numerical schemes based on MPI and OpenMP technologies have been created.
- Model calculations were carried out that demonstrated the operability and adequacy of the developed computing technology.

**Thank you for the attention!**